

# BioMon Sensor

## Datasheet

### Version 1.1

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#### SFH7060



#### Features:

- Multi chip package featuring three green, one red, one infrared emitter and one detector
- Small package: (WxDxH) 7.2 mm x 2.5 mm x 0.9 mm
- Light Barrier to block optical crosstalk
- Improved geometry for optimized signal quality

#### Applications

- Heart rate monitoring
- Pulse oximetry

#### for:

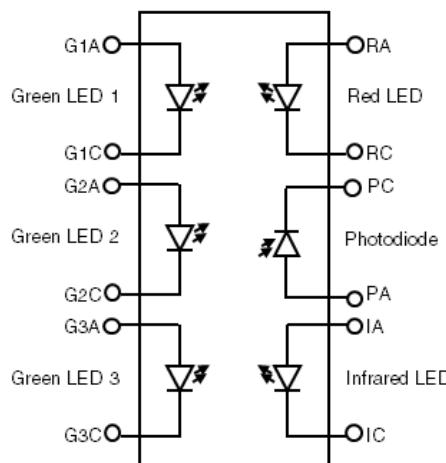
- Wearable devices (e.g. smart watches, fitness trackers, ...)
- Mobile devices

#### Ordering Information SFH7060

Type	Ordering Code
SFH7060	Q65111A7791

**Pin configuration**

Pin	Name	Function
1	RA	Red LED Anode
2	RC	Red LED Cathode
3	G1C	Green LED 1 Cathode
4	G1A	Green LED 1 Anode
5	G2A	Green LED 2 Anode
6	PA	Photodiode Anode
7	PC	Photodiode Cathode
8	G2C	Green LED 2 Cathode
9	G3A	Green LED 3 Anode
10	G3C	Green LED 3 Cathode
11	IC	Infrared LED Cathode
12	IA	Infrared LED Anode

**Top view****Block diagram**

**Maximum Ratings ( $T_A = 25^\circ\text{C}$ )**

Parameter	Symbol	Values	Unit
<b>General</b>			
Operating temperature range	$T_{op}$	-40 ... 85	°C
Storage temperature range	$T_{stg}$	-40 ... 85	°C
ESD withstand voltage (acc. to ANSI/ ESDA/ JEDEC JS-001 - HBM)	$V_{ESD}$	2	kV
<b>Infrared Emitter</b>			
Reverse Voltage	$V_R$	5	V
Forward current	$I_F(DC)$	60	mA
Surge current ( $t_p = 100 \mu\text{s}$ , D = 0)	$I_{FSM}$	1	A
<b>Red Emitter</b>			
Reverse voltage	$V_R$	12	V
Forward current	$I_F(DC)$	40	mA
Surge current ( $t_p = 100 \mu\text{s}$ , D = 0)	$I_{FSM}$	600	mA
<b>Green Emitters</b>			
Reverse voltage	$V_R$	5	V
Forward current (single operation)	$I_F(DC)$	25	mA
Forward current (all three green emitters operation)	$I_F(DC)$	15	mA
Surge current (single and all three emitters operation) ( $t_p = 100 \mu\text{s}$ , D = 0)	$I_{FSM}$	300	mA
<b>Detector</b>			
Reverse voltage	$V_R$	16	V

**Note:** The stated maximum ratings refer to single emitter chip operation, unless otherwise specified.

Characteristics ( $T_A = 25^\circ\text{C}$ )

Parameter		Symbol	Value	Unit
<b>Infrared Emitter</b>				
Wavelength of peak emission ( $I_F = 20 \text{ mA}$ , $t_p = 20 \text{ ms}$ )	(typ.)	$\lambda_{\text{peak}}$	950	nm
Centroid Wavelength ( $I_F = 20 \text{ mA}$ , $t_p = 20 \text{ ms}$ )	(typ. (max.))	$\lambda_{\text{centroid}}$	940 ( $\pm 10$ )	nm
Spectral bandwidth at 50% of $I_{\text{max}}$ ( $I_F = 20 \text{ mA}$ , $t_p = 20 \text{ ms}$ )	(typ.)	$\Delta\lambda$	42	nm
Half angle	(typ.)	$\varphi$	$\pm 60$	$^\circ$
Rise and fall time of $I_e$ (10% and 90% of $I_{e\text{max}}$ ) ( $I_F = 100 \text{ mA}$ , $t_p = 16 \mu\text{s}$ , $R_L = 50 \Omega$ )	(typ.)	$t_r, t_f$	16	ns
Forward voltage ( $I_F = 20 \text{ mA}$ , $t_p = 20 \text{ ms}$ )	(typ. (max.))	$V_F$	1.3 ( $\leq 1.8$ )	V
Reverse current ( $V_R = 5 \text{ V}$ )		$I_R$	not designed for reverse operation	$\mu\text{A}$
Radiant intensity ( $I_F = 20 \text{ mA}$ , $t_p = 20 \text{ ms}$ )	(typ.)	$I_e$	2	mW / sr
Total radiant flux ( $I_F = 20 \text{ mA}$ , $t_p = 20 \text{ ms}$ )	(typ.)	$\Phi_e$	5.3	mW
Temperature coefficient of $I_e$ or $\Phi_e$ ( $I_F = 20 \text{ mA}$ , $t_p = 20 \text{ ms}$ )	(typ.)	$TC_I$	-0.3	% / K
Temperature coefficient of $V_F$ ( $I_F = 20 \text{ mA}$ , $t_p = 20 \text{ ms}$ )	(typ.)	$TC_V$	-0.8	mV / K
Temperature coefficient of $\lambda_{\text{centroid}}$ ( $I_F = 20 \text{ mA}$ , $t_p = 20 \text{ ms}$ )	(typ.)	$TC_{\lambda_{\text{centroid}}}$	0.25	nm / K

Characteristics ( $T_A = 25^\circ\text{C}$ )

Parameter		Symbol	Value	Unit
<b>Red Emitter</b>				
Wavelength of peak emission ( $I_F = 20 \text{ mA}$ )	(typ.)	$\lambda_{\text{peak}}$	660	nm
Centroid Wavelength ( $I_F = 20 \text{ mA}$ )	(typ. (max.))	$\lambda_{\text{centroid}}$	655 ( $\pm 3$ )	nm
Spectral bandwidth at 50% of $I_{\text{max}}$ ( $I_F = 20 \text{ mA}$ )	(typ.)	$\Delta\lambda$	17	nm
Half angle	(typ.)	$\varphi$	$\pm 60$	$^\circ$
Rise and fall time of $I_e$ (10% and 90% of $I_{e\text{max}}$ ) ( $I_F = 100 \text{ mA}$ , $t_p = 16 \mu\text{s}$ , $R_L = 50 \Omega$ )	(typ.)	$t_r, t_f$	17	ns
Forward voltage ( $I_F = 20 \text{ mA}$ )	(typ. (max.))	$V_F$	2.1 ( $\leq 2.8$ )	V
Reverse current ( $V_R = 12V$ )		$I_R$	not designed for reverse operation	$\mu\text{A}$
Radiant intensity ( $I_F = 20 \text{ mA}$ , $t_p = 20 \text{ ms}$ )	(typ.)	$I_e$	2.6	mW / sr
Total radiant flux ( $I_F = 20 \text{ mA}$ , $t_p = 20 \text{ ms}$ )	(typ.)	$\Phi_e$	6.4	mW
Temperature coefficient of $\lambda_{\text{centroid}}$ ( $I_F = 20 \text{ mA}$ , $-10^\circ\text{C} \leq T \leq 100^\circ\text{C}$ )	(typ.)	$TC_{\lambda,\text{centroid}}$	0.13	nm / K

**Characteristics ( $T_A = 25^\circ\text{C}$ )**

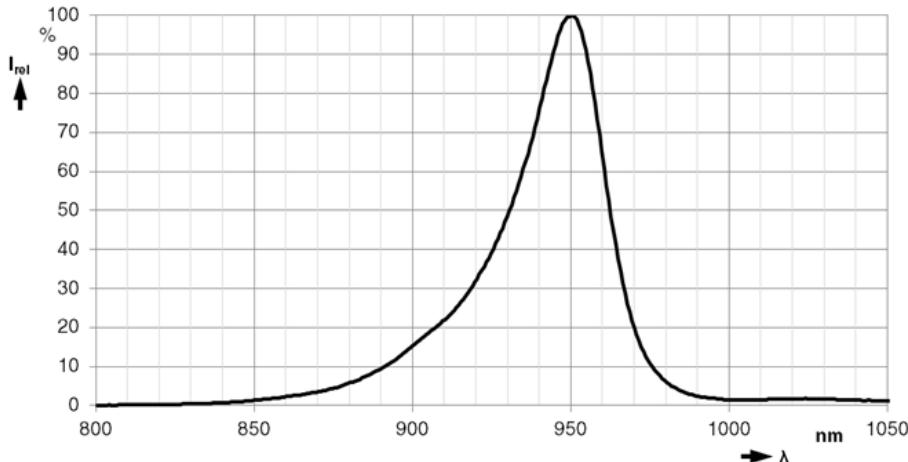
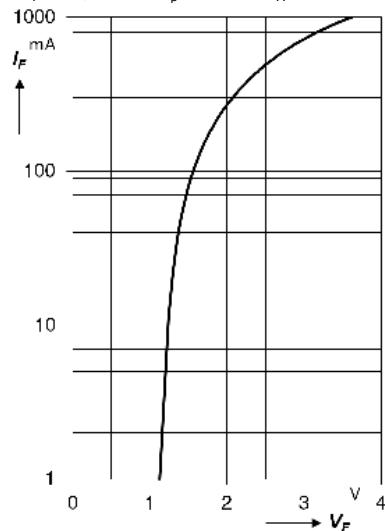
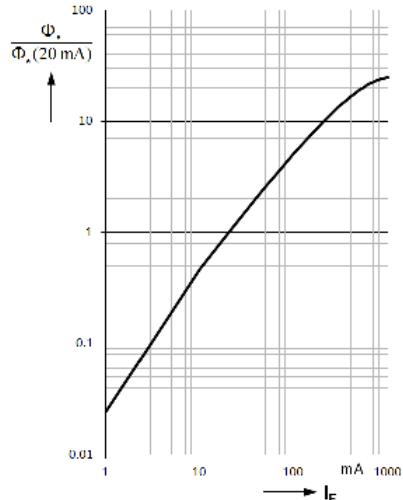
Parameter		Symbol	Value	Unit
<b>Green Emitter (single emitter)</b>				
Wavelength of peak emission ( $I_F = 20 \text{ mA}$ )	(typ.)	$\lambda_{\text{peak}}$	530	nm
Centroid Wavelength ( $I_F = 20 \text{ mA}$ )	(typ. (max.))	$\lambda_{\text{centroid}}$	535 ( $\pm 10$ )	nm
Spectral bandwidth at 50% of $I_{\text{max}}$ ( $I_F = 20 \text{ mA}$ )	(typ.)	$\Delta\lambda$	34	nm
Half angle	(typ.)	$\varphi$	$\pm 60$	$^\circ$
Rise and fall time of $I_e$ (10% and 90% of $I_{e\text{max}}$ ) ( $I_F = 100 \text{ mA}$ , $t_p = 16 \mu\text{s}$ , $R_L = 50 \Omega$ )	(typ.)	$t_r, t_f$	32	ns
Forward voltage ( $I_F = 20 \text{ mA}$ )	(typ. (max.))	$V_F$	3.2 ( $\leq 3.70$ )	V
Reverse current ( $V_R = 5 \text{ V}$ )		$I_R$	not designed for reverse operation	$\mu\text{A}$
Radiant intensity ( $I_F = 20 \text{ mA}$ , $t_p = 20 \text{ ms}$ )	(typ.)	$I_e$	1.4	mW / sr
Total radiant flux ( $I_F = 20 \text{ mA}$ , $t_p = 20 \text{ ms}$ )	(typ.)	$\Phi_e$	3.4	mW
Temperature coefficient of $\lambda_{\text{centroid}}$ ( $I_F = 20 \text{ mA}$ , $-10^\circ\text{C} \leq T \leq 100^\circ\text{C}$ )	(typ.)	$TC_{\lambda,\text{centroid}}$	0.02	nm / K
Temperature coefficient of $V_F$ ( $I_F = 20 \text{ mA}$ , $-10^\circ\text{C} \leq T \leq 100^\circ\text{C}$ )	(typ.)	$TC_V$	-4.0	mV / K

Characteristics ( $T_A = 25^\circ\text{C}$ )

Parameter		Symbol	Value	Unit
<b>Detector</b>				
Photocurrent ( $E_e = 0.1 \text{ mW/cm}^2$ , $\lambda = 535\text{nm}$ , $V_R = 5 \text{ V}$ )	(typ.)	$I_{P,535}$	0.42	$\mu\text{A}$
Photocurrent ( $E_e = 0.1 \text{ mW/cm}^2$ , $\lambda = 655 \text{ nm}$ , $V_R = 5 \text{ V}$ )	(typ.)	$I_{P,655}$	0.76	$\mu\text{A}$
Photocurrent ( $E_e = 0.1 \text{ mW/cm}^2$ , $\lambda = 940 \text{ nm}$ , $V_R = 5 \text{ V}$ )	(typ.)	$I_{P,940}$	1.3	$\mu\text{A}$
Wavelength of max. sensitivity	(typ.)	$\lambda_{S \max}$	920	nm
Spectral range of sensitivity	(typ.)	$\lambda_{10\%}$	400 ... 1100	nm
Radiation sensitive area	(typ.)	A	1.7	$\text{mm}^2$
Dimensions of radiant sensitive area	(typ.)	L x W	1.3 x 1.3	mm x mm
Dark current ( $V_R = 5 \text{ V}$ , $E_e = 0 \text{ mW/cm}^2$ )	(typ. (max.))	$I_R$	1 ( $\leq 5$ )	nA
Spectral sensitivity of the chip ( $\lambda = 535 \text{ nm}$ )	(typ.)	$S_{\lambda,535}$	0.27	A / W
Spectral sensitivity of the chip ( $\lambda = 655\text{nm}$ )	(typ.)	$S_{\lambda,655}$	0.47	A / W
Spectral sensitivity of the chip ( $\lambda = 940 \text{ nm}$ )	(typ.)	$S_{\lambda,940}$	0.77	A / W
Open-circuit voltage ( $E_e = 0.1 \text{ mW/cm}^2$ , $\lambda = 535 \text{ nm}$ )	(typ.)	$V_{O,535}$	240	mV
Short-circuit current ( $E_e = 0.1 \text{ mW/cm}^2$ , $\lambda = 535 \text{ nm}$ )	(typ.)	$I_{SC,535}$	0.40	$\mu\text{A}$
Open-circuit voltage ( $E_e = 0.1 \text{ mW/cm}^2$ , $\lambda = 655\text{nm}$ )	(typ.)	$V_{O,655}$	250	mV
Short-circuit current ( $E_e = 0.1 \text{ mW/cm}^2$ , $\lambda = 655 \text{ nm}$ )	(typ.)	$I_{SC,655}$	0.71	$\mu\text{A}$
Open-circuit voltage ( $E_e = 0.1 \text{ mW/cm}^2$ , $\lambda = 940 \text{ nm}$ )	(typ.)	$V_{O,940}$	270	mV
Short-circuit current ( $E_e = 0.1 \text{ mW/cm}^2$ , $\lambda = 940 \text{ nm}$ )	(typ.)	$I_{SC,940}$	1.2	$\mu\text{A}$

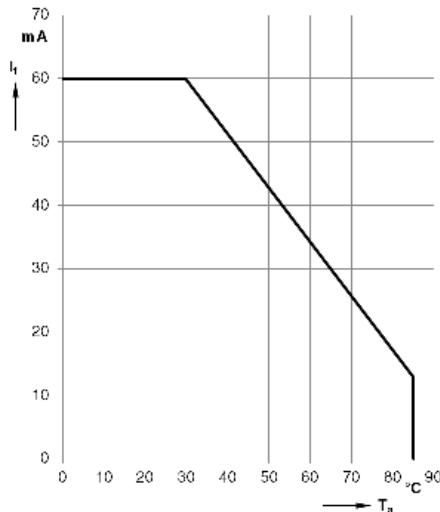
**Characteristics ( $T_A = 25^\circ\text{C}$ )**

Parameter		Symbol	Value	Unit
Rise and fall time ( $V_R = 3.3 \text{ V}$ , $R_L = 50 \Omega$ , $\lambda = 940 \text{ nm}$ )	(typ.)	$t_r, t_f$	2.3	$\mu\text{s}$
Forward voltage ( $I_F = 10 \text{ mA}$ , $E = 0 \text{ mW/cm}^2$ )	(typ.)	$V_F$	0.9	V
Capacitance ( $V_R = 5 \text{ V}$ , $f = 1 \text{ MHz}$ , $E = 0 \text{ mW/cm}^2$ )	(typ.)	$C_0$	5	pF

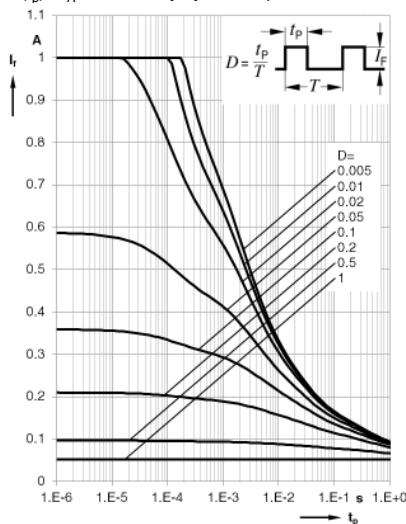
**Diagrams for infrared emitter****Relative spectral emission<sup>1)</sup>** $I_{\text{rel}} = f(\lambda), T_A = 25^\circ\text{C}, I_F = 20 \text{ mA}$ **Forward current<sup>1)</sup>** $I_F = f(V_F)$ , single pulse,  $t_p = 100 \mu\text{s}$ ,  $T_A = 25^\circ\text{C}$ **Relative radiant flux<sup>1)</sup>** $\Phi_e / \Phi_e(20 \text{ mA}) = f(I_F)$ , single pulse,  $t_p = 25 \mu\text{s}$ ,  $T_A = 25^\circ\text{C}$ 

**Diagrams for infrared emitter****Max. permissible forward current**<sup>1)</sup>

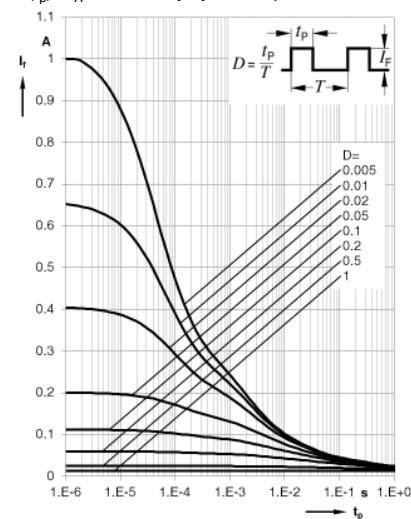
$$I_{F,\max} = f(T_A), R_{thJA} = 800 \text{ K/W}$$

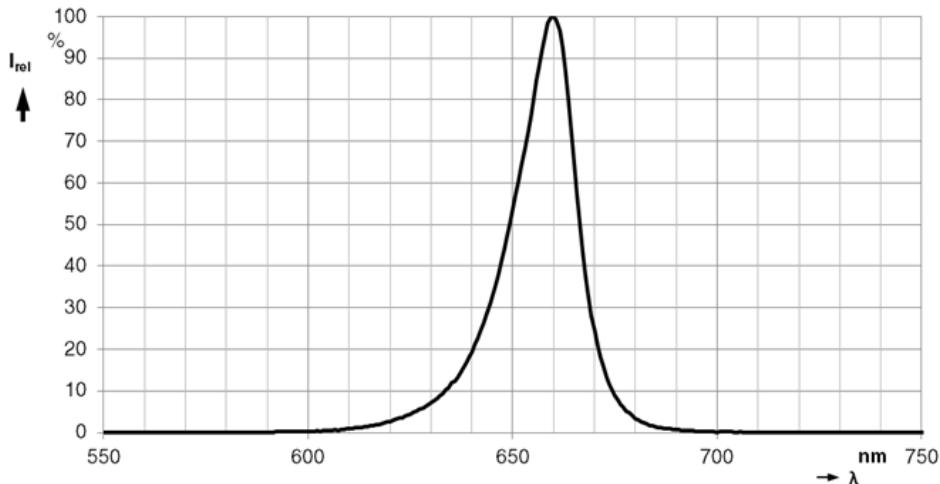
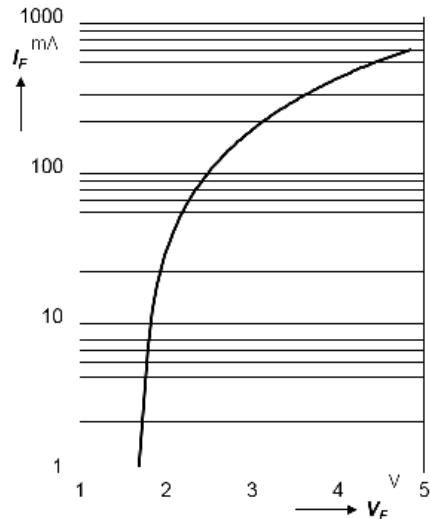
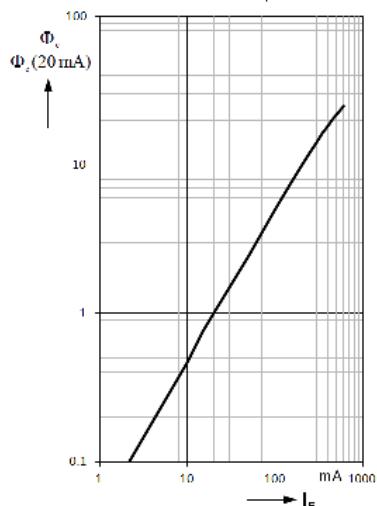
**Permissible pulse handling capability**<sup>1)</sup>

$$I_F = f(t_p), T_A = 40^\circ\text{C}, \text{duty cycle } D = \text{parameter}$$

**Permissible pulse handling capability**<sup>1)</sup>

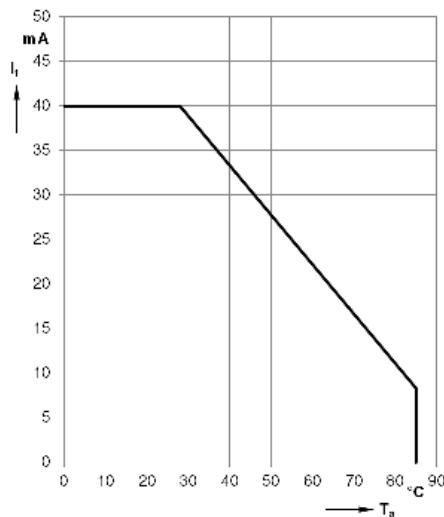
$$I_F = f(t_p), T_A = 85^\circ\text{C}, \text{duty cycle } D = \text{parameter}$$



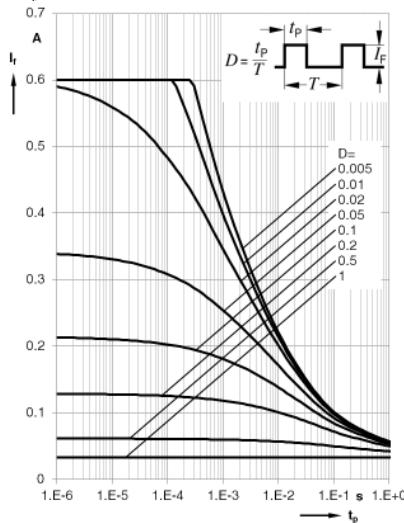
**Diagrams for red emitter****Relative spectral emission<sup>1)</sup>** $I_{\text{rel}} = f(\lambda)$ ,  $T_A = 25^\circ\text{C}$ ,  $I_F = 20 \text{ mA}$ **Forward current<sup>1)</sup>** $I_F = f(V_F)$ ,  $T_A = 25^\circ\text{C}$ **Relative radiant flux<sup>1)</sup>** $\Phi_e / \Phi_e(20 \text{ mA}) = f(I_F)$ , single pulse,  $t_p = 25 \mu\text{s}$ ,  $T_A = 25^\circ\text{C}$ 

**Diagrams for red emitter****Max. permissible forward current<sup>1)</sup>**

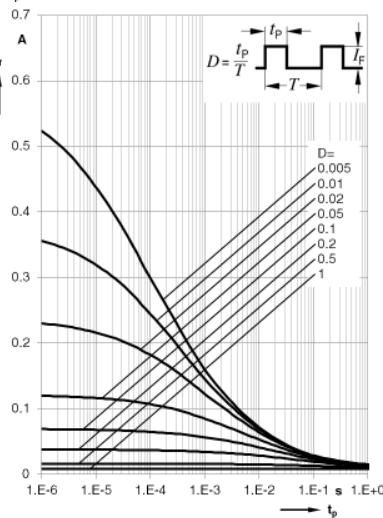
$$I_{F,\max} = f(T_A), R_{thJA} = 800 \text{ K/W}$$

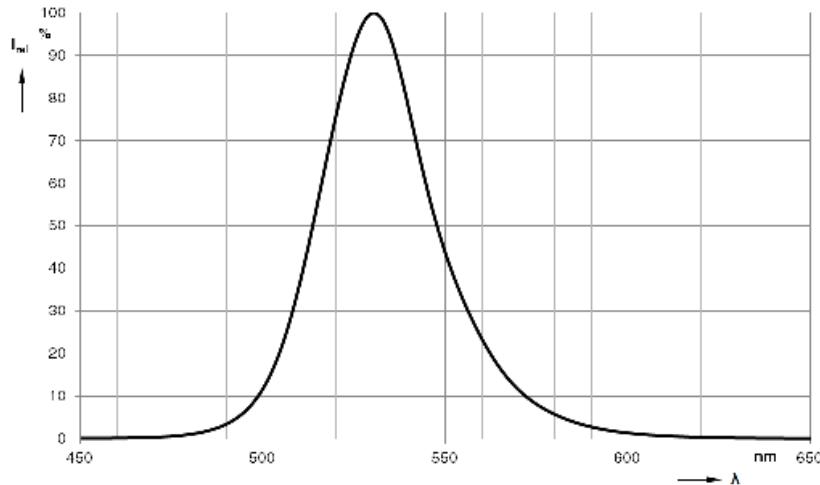
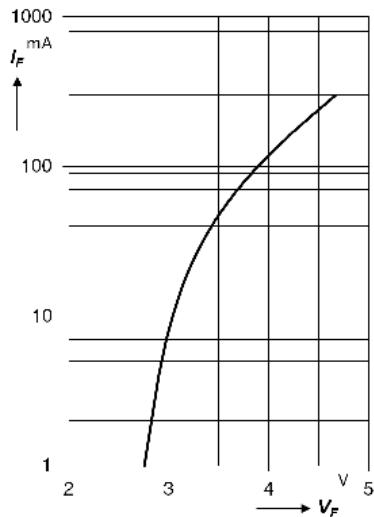
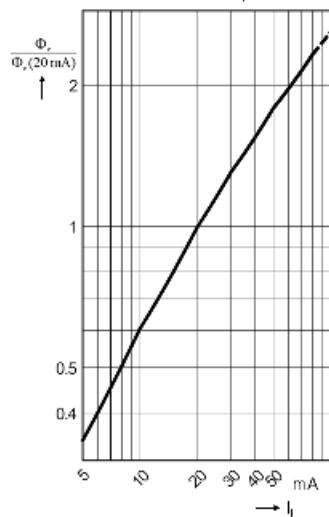
**Permissible pulse handling capability<sup>1)</sup>**

$$I_F = f(t_p), T_A = 40^\circ\text{C}, \text{duty cycle } D = \text{parameter}$$

**Permissible pulse handling capability<sup>1)</sup>**

$$I_F = f(t_p), T_A = 85^\circ\text{C}, \text{duty cycle } D = \text{parameter}$$

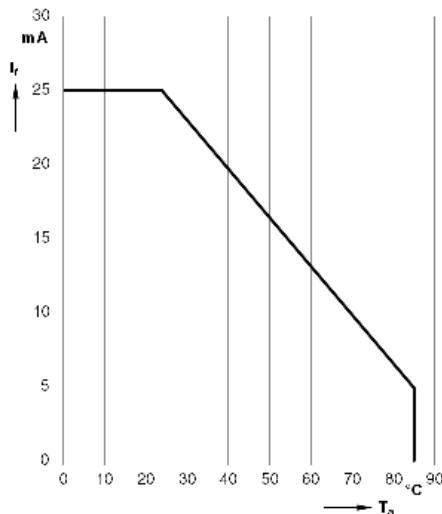


**Diagrams for green emitters****Relative spectral emission<sup>1)</sup>** $I_{\text{rel}} = f(\lambda)$ ,  $T_A = 25^\circ\text{C}$ ,  $I_F = 20 \text{ mA}$ **Forward current<sup>1)</sup>** $I_F = f(V_F)$ ,  $T_A = 25^\circ\text{C}$ **Relative radiant flux<sup>1)</sup>** $\Phi_e / \Phi_e(20 \text{ mA}) = f(I_F)$ , single pulse,  $t_p = 25 \mu\text{s}$ ,  $T_A = 25^\circ\text{C}$ 

### Diagrams for green emitters

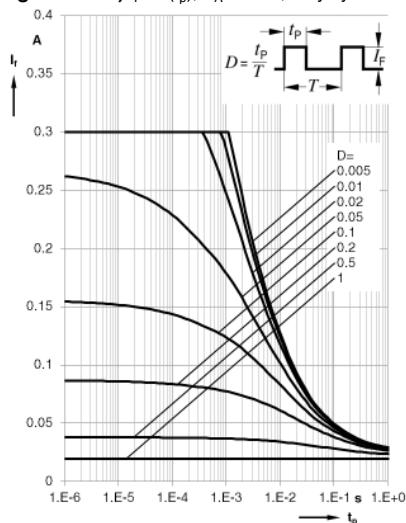
**Max. permissible forward current** <sup>1)</sup>

(single emitter)  $I_{F,\max} = f(T_A)$ ,  $R_{thJA} = 800 \text{ K/W}$



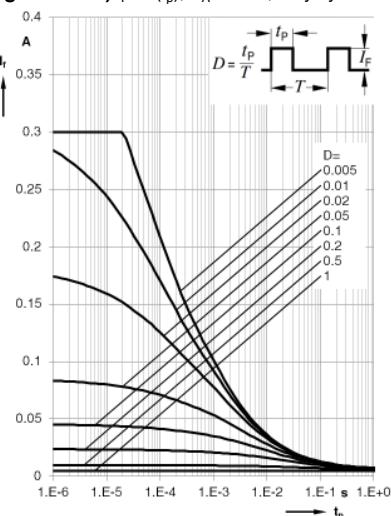
**Permissible pulse handling capability** <sup>1)</sup>

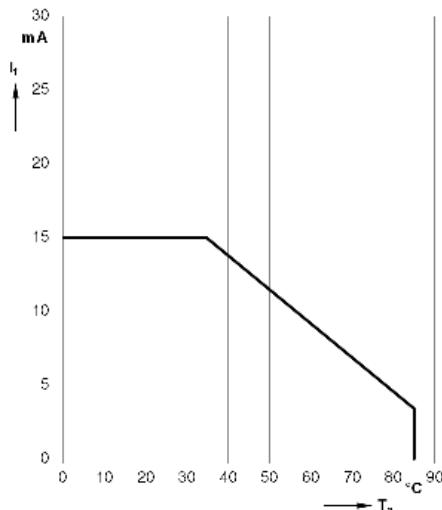
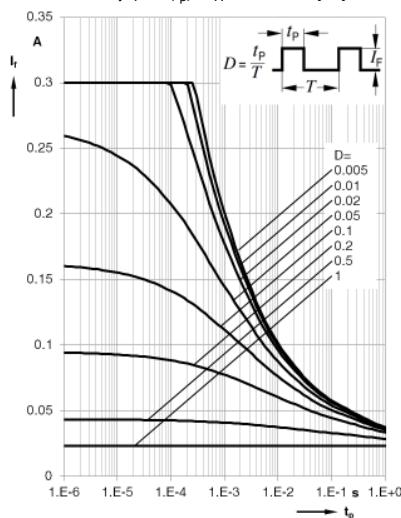
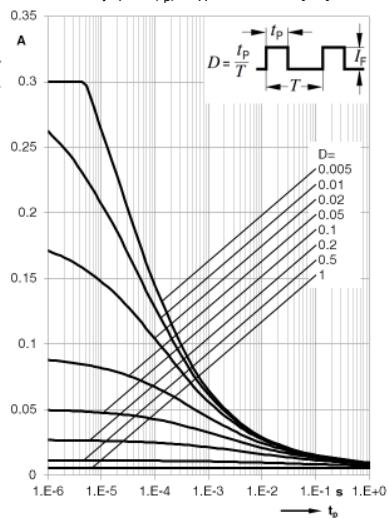
(single emitter)  $I_F = f(t_p)$ ,  $T_A = 40^\circ\text{C}$ , duty cycle D

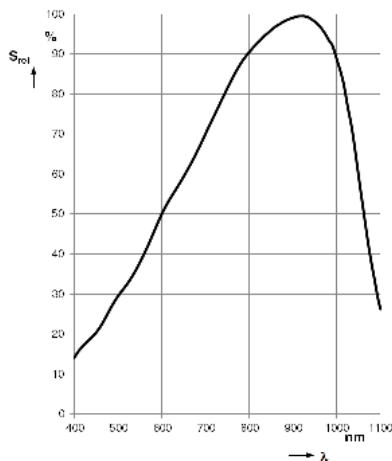
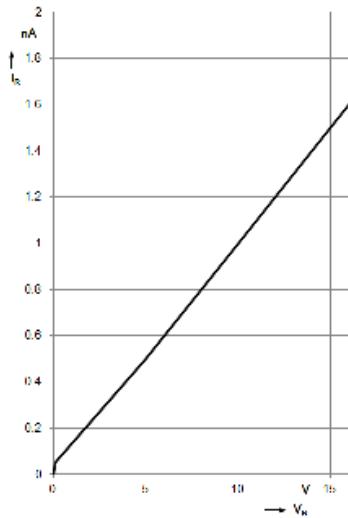
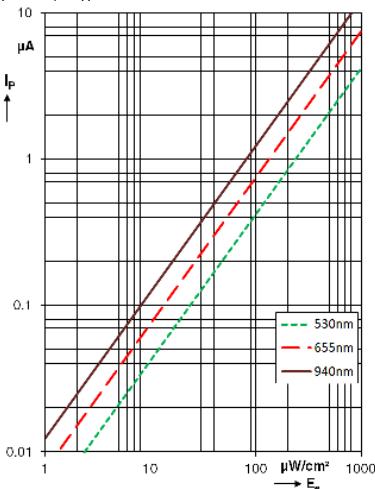


**Permissible pulse handling capability** <sup>1)</sup>

(single emitter)  $I_F = f(t_p)$ ,  $T_A = 85^\circ\text{C}$ , duty cycle D

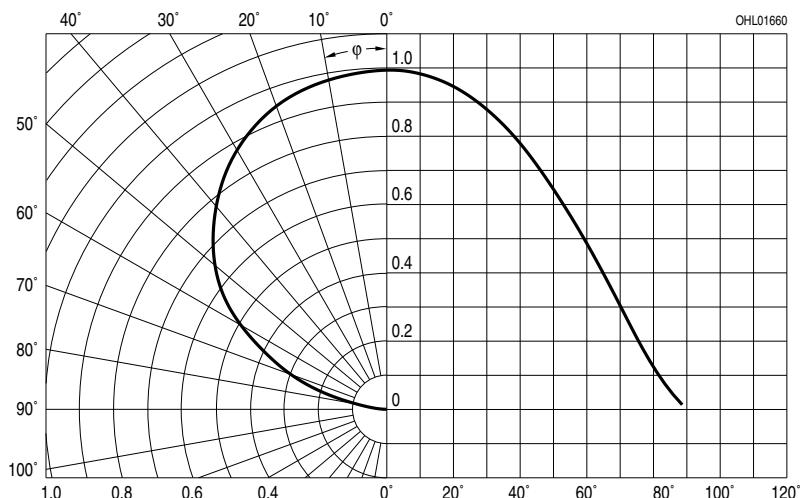


**Diagrams for green emitters****Max. permissible forward current** <sup>1)</sup>(three emitters)  $I_{F,\max} = f(T_A)$ ,  $R_{thJA} = 800 \text{ K/W}$ **Permissible pulse handling capability** <sup>1)</sup>(three emitters)  $I_F = f(t_p)$ ,  $T_A = 40^\circ\text{C}$ , duty cycle D**Permissible pulse handling capability** <sup>1)</sup>(three emitters)  $I_F = f(t_p)$ ,  $T_A = 85^\circ\text{C}$ , duty cycle D

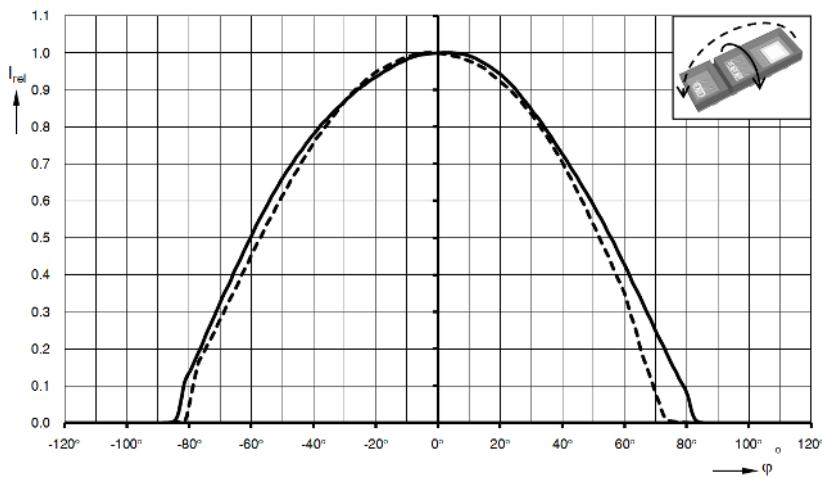
**Diagrams for detector****Relative spectral sensitivity<sup>1)</sup>** $S_{\text{rel}} = f(\lambda)$ ,  $T_A = 25^\circ\text{C}$ **Dark current<sup>1)</sup>** $I_D = f(V_R)$ ,  $E = 0 \text{ mW/cm}^2$ ,  $T_A = 25^\circ\text{C}$ **Photocurrent<sup>1)</sup>** $I_P(V_R = 5 \text{ V})$ ,  $T_A = 25^\circ\text{C}$ **Capacitance<sup>1)</sup>** $C = f(V_R)$ ,  $f = 1 \text{ MHz}$ ,  $E = 0 \text{ mW/cm}^2$ ,  $T_A = 25^\circ\text{C}$ 

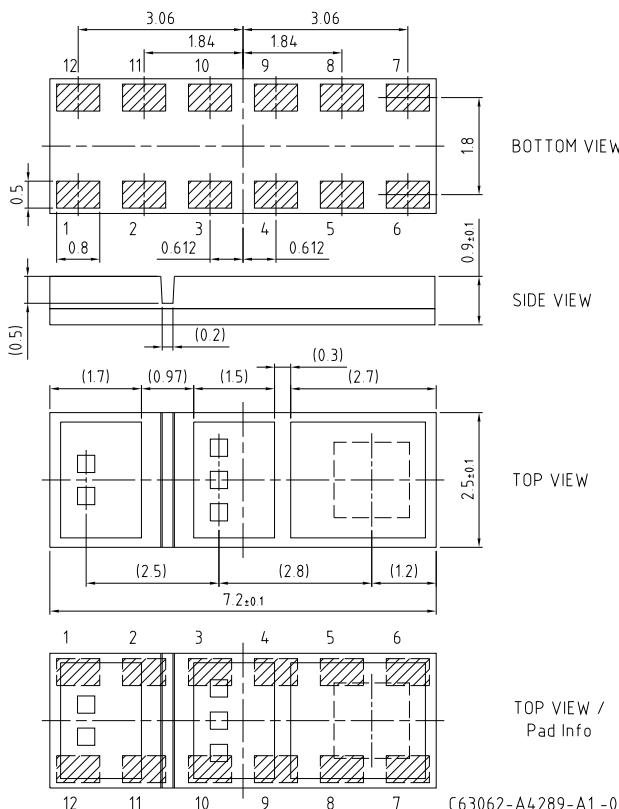
**Directional characteristics of detector<sup>1)</sup>**

$$S_{\text{rel}} = f(\varphi)$$

**Radiation characteristics of emitters<sup>1)</sup>**

$$I_{\text{rel}} = f(\varphi)$$



**Package Outline**

Pin	Name	Function
1	RA	Red LED Anode
2	RC	RED LED Cathode
3	G1C	Green LED 1 Cathode
4	G1A	Green LED 1 Anode
5	G2A	Green LED 2 Anode
6	PA	Photodiode Anode
7	PC	Photodiode Cathode
8	G2C	Green LED 2 Cathode
9	G3A	Green LED 3 Anode
10	G3C	Green LED 3 Cathode
11	IC	Infrared LED Cathode
12	IA	Infrared LED Anode

Dimensions in mm.

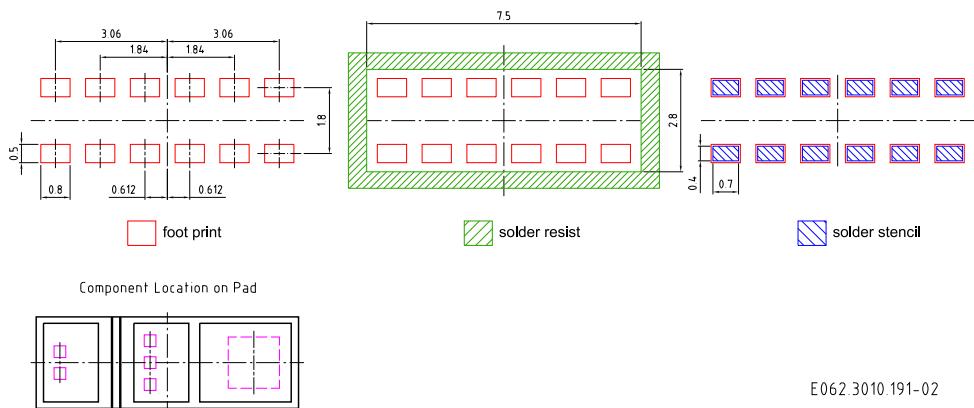
**Package:**

chip on board

**Approximate weight:**

28 mg

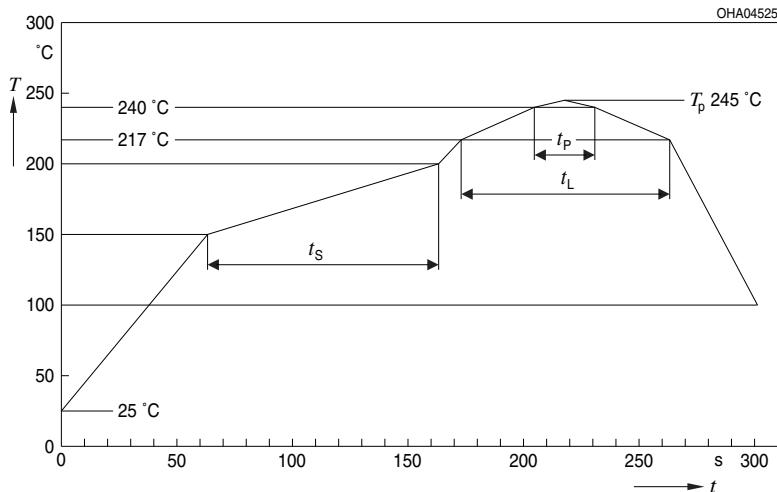
### Recommended solder pad design



Dimensions in mm (inch).

### Reflow Soldering Profile

Product complies to MSL Level 4 acc. to JEDEC J-STD-020D.01



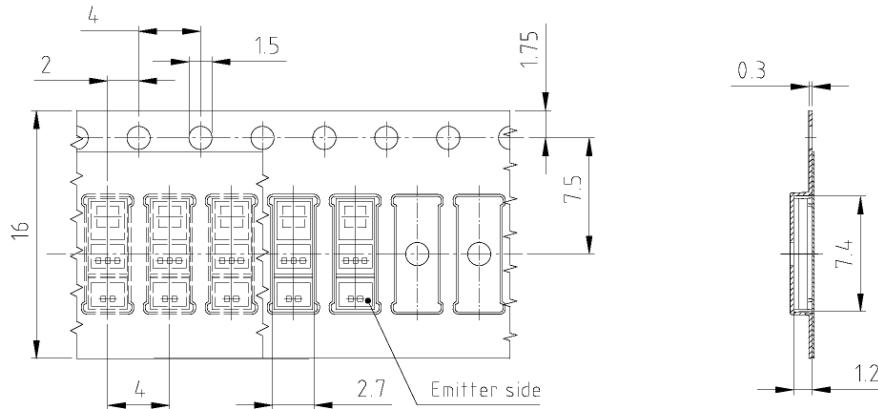
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Profile Feature Profil-Charakteristik	Symbol Symbol	Pb-Free (SnAgCu) Assembly			Unit Einheit
		Minimum	Recommendation	Maximum	
Ramp-up rate to preheat*) 25 °C to 150 °C			2	3	K/s
Time $t_S$ $T_{Smin}$ to $T_{Smax}$	$t_S$	60	100	120	s
Ramp-up rate to peak*) $T_{Smax}$ to $T_P$			2	3	K/s
Liquidus temperature	$T_L$		217		°C
Time above liquidus temperature	$t_L$		80	100	s
Peak temperature	$T_P$		245	260	°C
Time within 5 °C of the specified peak temperature $T_P - 5$ K	$t_P$	10	20	30	s
Ramp-down rate* $T_P$ to 100 °C			3	6	K/s
Time 25 °C to $T_P$				480	s

All temperatures refer to the center of the package, measured on the top of the component

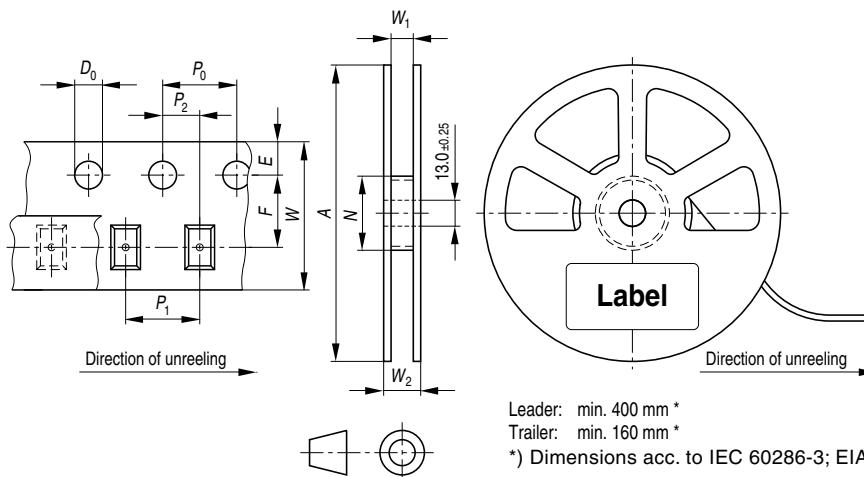
\* slope calculation DT/Dt: Dt max. 5 s; fulfillment for the whole T-range

## Method of Taping



C63062-A4289-B6 -02

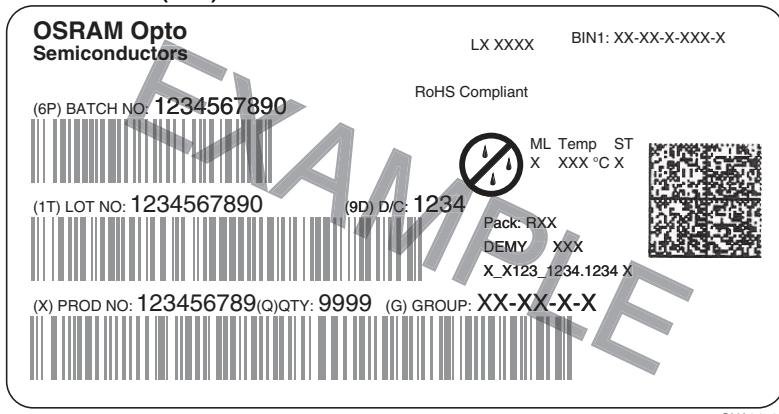
Dimensions in mm [inch].

**Tape and Reel**16 mm tape with 3000 pcs. on  $\varnothing$  180 mm reel**Tape Dimensions [mm]**

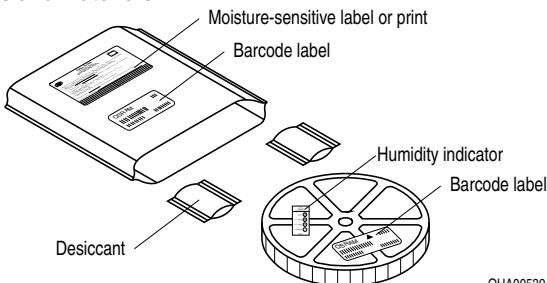
W	P <sub>0</sub>	P <sub>1</sub>	P <sub>2</sub>	D <sub>0</sub>	E	F
16 +0.3 / -0.1	4 ±0.1	4 ±0.1	2 ±0.05	1.5 ±0.1	1.75 ±0.1	7.5 ±0.05

**Reel Dimensions [mm]**

A	W	N <sub>min</sub>	W <sub>1</sub>	W <sub>2max</sub>
180	16	60	16.4 +2	22.4

**Barcode-Product-Label (BPL)**

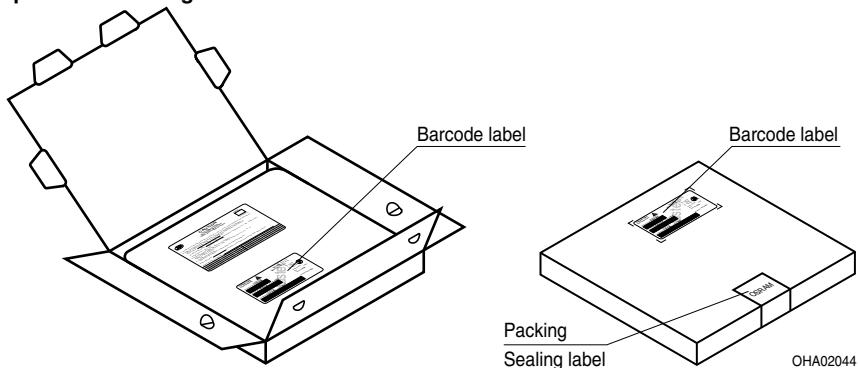
OHA04563

**Dry Packing Process and Materials**

OHA00539

**Note:**

Moisture-sensitive product is packed in a dry bag containing desiccant and a humidity card. Regarding dry pack you will find further information in the internet. Here you will also find the normative references like JEDEC.

**Transportation Packing and Materials****Dimensions of transportation box in mm**

Width	Length	Height
195 ± 5	195 ± 5	42 ± 5

## Disclaimer

Language english will prevail in case of any discrepancies or deviations between the two language wordings.

### Attention please!

The information describes the type of component and shall not be considered as assured characteristics.  
Terms of delivery and rights to change design reserved. Due to technical requirements components may contain dangerous substances.

For information on the types in question please contact our Sales Organization.?If printed or downloaded, please find the latest version in the Internet.

### Packing

Please use the recycling operators known to you. We can also help you – get in touch with your nearest sales office.  
?By agreement we will take packing material back, if it is sorted. You must bear the costs of transport. For packing material that is returned to us unsorted or which we are not obliged to accept, we shall have to invoice you for any costs incurred.

### Components used in life-support devices or systems must be expressly authorized for such purpose!

Critical components\* may only be used in life-support devices\*\* or systems with the express written approval of OSRAM OS.

\*) A critical component is a component used in a life-support device or system whose failure can reasonably be expected to cause the failure of that life-support device or system, or to affect its safety or the effectiveness of that device or system.

\*\*) Life support devices or systems are intended (a) to be implanted in the human body, or (b) to support and/or maintain and sustain human life. If they fail, it is reasonable to assume that the health and the life of the user may be endangered.

## Glossary

**1) Typical Values:** Due to the special conditions of the manufacturing processes of LED and photodiodes, the typical data or calculated correlations of technical parameters can only reflect statistical figures. These do not necessarily correspond to the actual parameters of each single product, which could differ from the typical data and calculated correlations or the typical characteristic line. If requested, e.g. because of technical improvements, these typ. data will be changed without any further notice.

